

Features

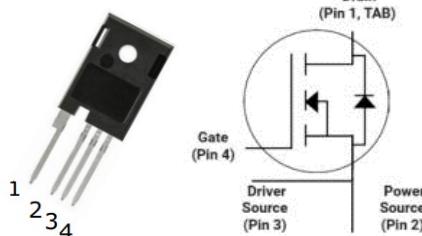
- High Blocking Voltage with Low On-Resistance
- High Speed Switching with Low Capacitances
- Avalanche Ruggedness

Product Summary

V _{DS}	1200V
R _{DS(on)_typ}	160mΩ
I _D	17A

Applications

- Solar Inverters
- Switch Mode Power Supplies
- High Voltage DC-DC Converters
- Battery Chargers



Package Marking and Ordering Information

Part #	Marking	Package
T1M160120K	1M160120K	TO-247-4

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source voltage	V _{DS}	1200	V
Continuous drain current	I _D	17	A
T _C = 25°C , V _{GS} = 18V		12	
T _C = 100°C, V _{GS} = 18V			
Pulsed drain current (T _C = 25°C, t _p limited by T _{jmax})	I _D pulse	34	A
Gate-Source voltage	V _{GS}	-4/+18	V
Gate-Source voltage (Absolute maximum values)	V _{GSmax}	-8/+22	V
Power dissipation (T _C = 25°C)	P _{tot}	116	W
Operating junction and storage temperature	T _j , T _{stg}	-55...+175	°C

- Example of acceptable V_{GS} waveform



Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal resistance, junction – case. Max	R_{thJC}	1.29	°C/W
Thermal resistance, junction – ambient. Max	R_{thJA}	40	

Electrical Characteristic (at $T_j = 25$ °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.		

Static Characteristic

Drain-source breakdown voltage	BV_{DSS}	1200	-	-	V	$V_{GS}=0V, I_D=100\mu A$
Gate threshold voltage	$V_{GS(th)}$	2	3.1	4	V	$V_{DS}=V_{GS}, I_D=2.3mA$
Zero gate voltage drain current	I_{DSS}	-	1	20	μA	$V_{DS}=1200V, V_{GS}=0V$
		-	5	-		$T_C=25^\circ C$
Gate-source leakage current	I_{GSS}	-		100	nA	$V_{GS}=18V, V_{DS}=0V$
Drain-source on-state resistance	$R_{DS(on)}$	-	160	208	$m\Omega$	$V_{GS}=18V, I_D=8A, T_j=25^\circ C$
		-	250	-		$T_j=175^\circ C$
Transconductance	g_{fs}	-	5	-	S	$V_{DS}=20V, I_D=8A$

Dynamic Characteristic

Input Capacitance	C_{iss}	-	624	-	pF	$V_{DS} = 1000V$ $V_{GS} = 0V$ $T_J = 25^\circ C$ $V_{AC} = 25mV$ $f = 1MHz$
Output Capacitance	C_{oss}	-	42	-		
Reverse Transfer Capacitance	C_{rss}	-	6	-		
Gate Total Charge	Q_G	-	37.4	-	nC	$V_{DS} = 800V$ $V_{GS} = 0/18V$ $I_D = 8A$ $I_G = 10mA$
Gate-Source charge	Q_{gs}	-	5.3	-		
Gate-Drain charge	Q_{gd}	-	20.6	-		
Turn-On Switching Energy	E_{ON}	-	11	-	μJ	$V_{DD}=800V$, $V_{GS}=-4/18V$ $R_G=5\Omega$, $I_D=8A$ Inductive Load, $T_J=25^\circ C$
Turn-Off Switching Energy	E_{OFF}	-	230	-		
Turn-on delay time	$t_{d(on)}$	-	12.25	-		
Rise time	t_r	-	18.68	-	ns	
Turn-off delay time	$t_{d(off)}$	-	17.37	-		
Fall time	t_f	-	11.82	-		
Gate resistance	R_G	-	3.3	-	Ω	$V_{AC} = 25mV$, $f=1MHz$

Body Diode Characteristic

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.		
Body Diode Forward Voltage	V_{SD}		3.6		V	$V_{GS} = 0V, I_{SD} = 4A$, $T_J = 25^\circ C$
			3.2			$V_{GS} = 0V, I_{SD} = 4A$, $T_J = 175^\circ C$
Body Diode Reverse Recovery Time	t_{rr}	-	13.5	-	ns	$V_R = 800V$, $V_{GS} = 0V$ $I_D = 8A$
Body Diode Reverse Recovery Charge	Q_{rr}	-	36.8	-	nC	$di/dt = 800A/\mu S$ $T_J = 25^\circ C$

Typical Performance Characteristics

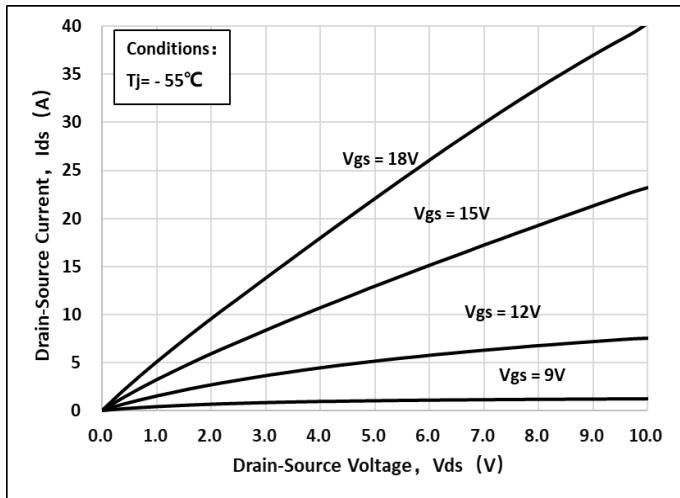
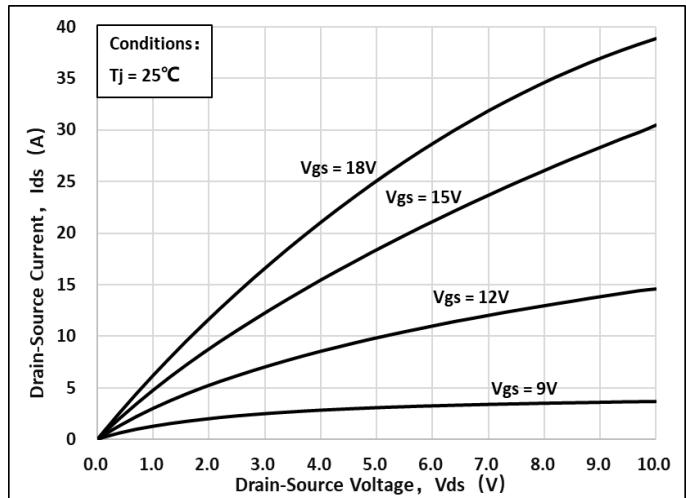
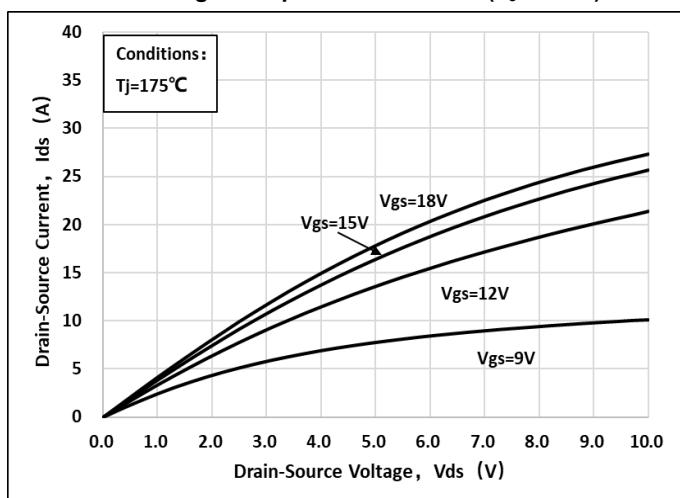
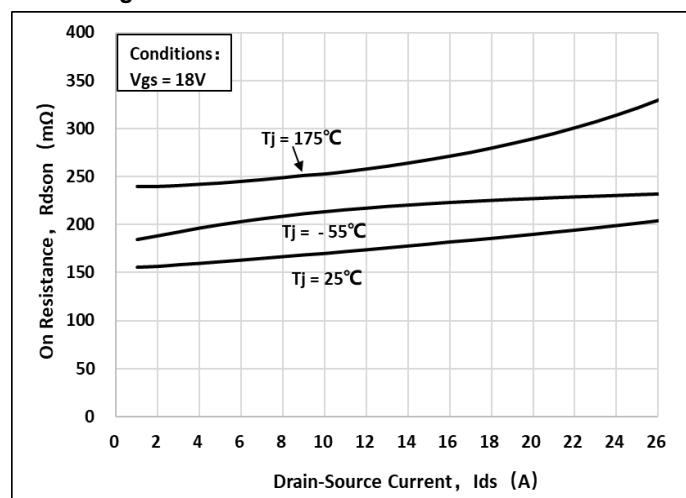
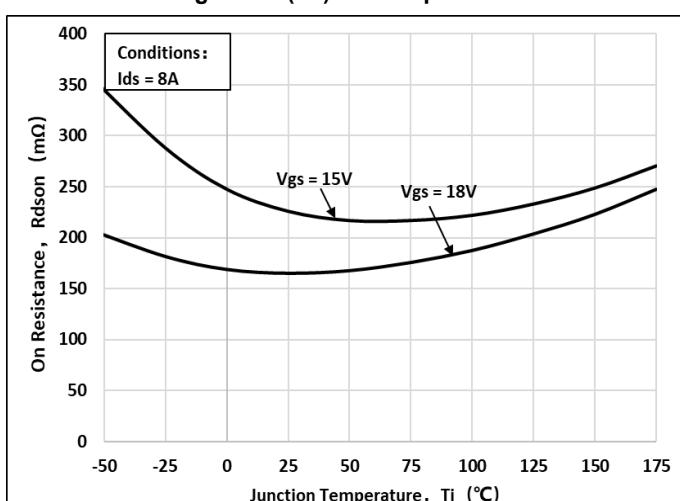
Fig 1. Output Characteristic ($T_J = -55^\circ\text{C}$)Fig 2. Output Characteristic ($T_J = 25^\circ\text{C}$)Fig 3. Output Characteristic ($T_J = 175^\circ\text{C}$)Fig 4: $R_{ds(on)}$ Vs Ids CharacteristicFig 5: $R_{ds(on)}$ vs. Temperature

Fig 6: Transfer Characteristic

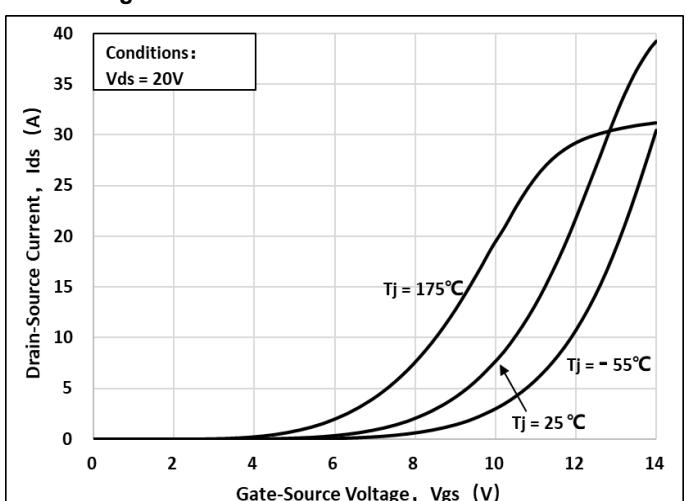


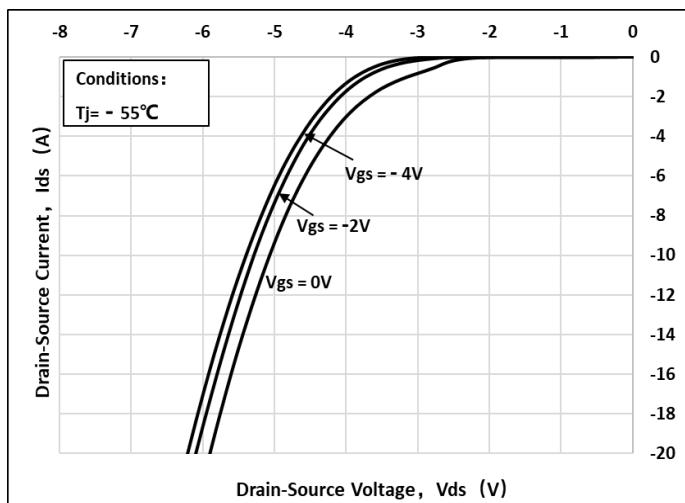
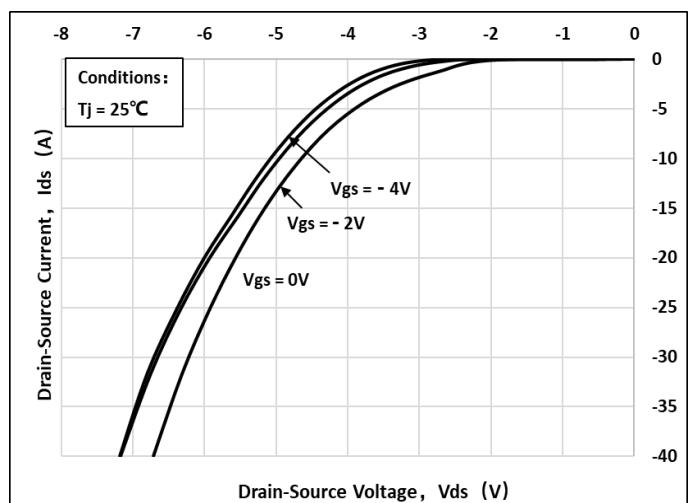
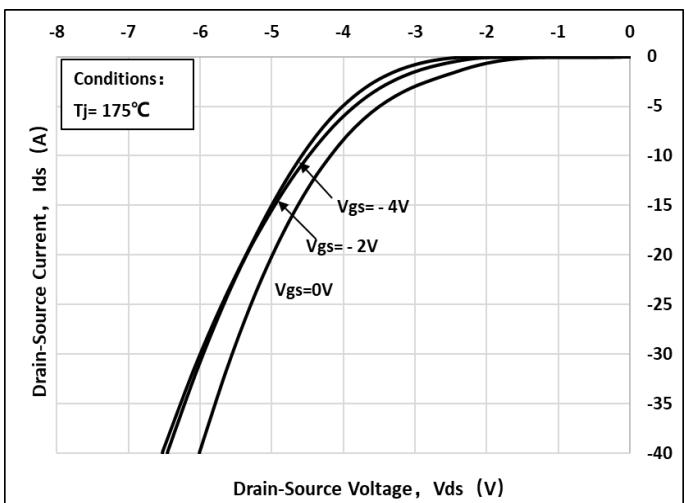
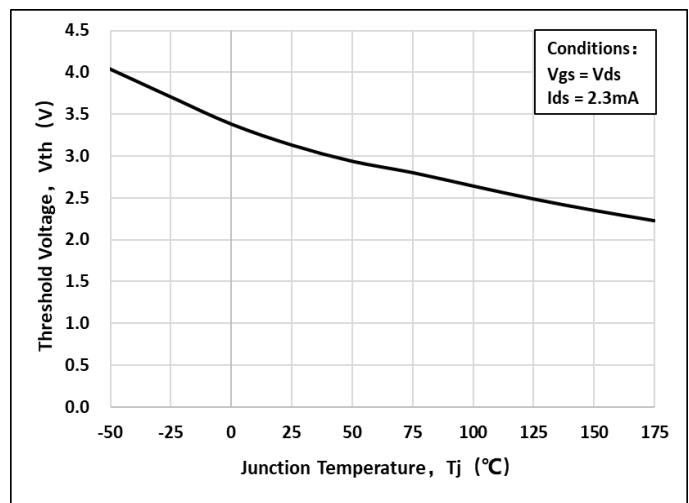
Fig 7: Body-diode Characteristic ($T_J = -55^\circ\text{C}$)Fig 8: Body-diode Characteristic ($T_J = 25^\circ\text{C}$)Fig 9: Body-diode Characteristic ($T_J = 175^\circ\text{C}$)Fig 10: V_{TH} Vs T_J Temperature Characteristic

Fig 11: Gate Charge Characteristics

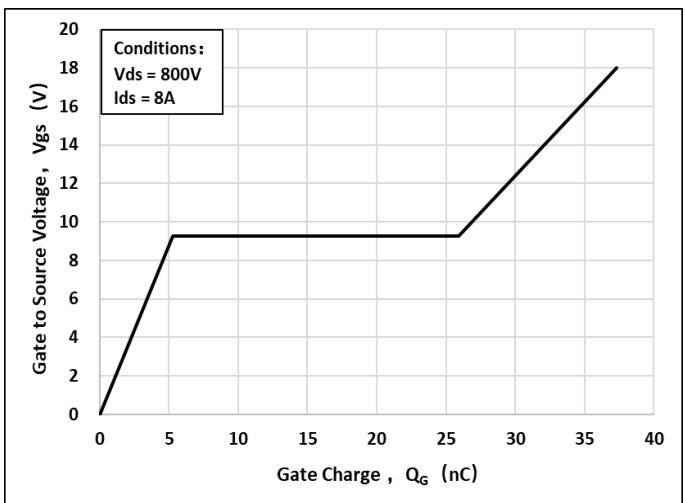
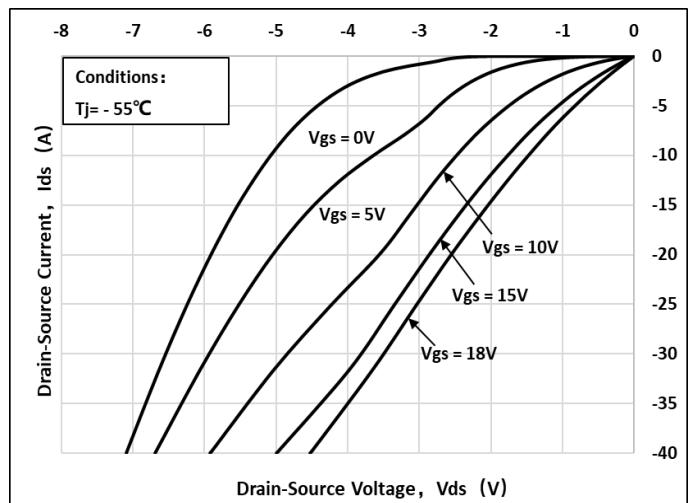
Fig 12: 3rd Quadrant Characteristic ($T_J = -55^\circ\text{C}$)

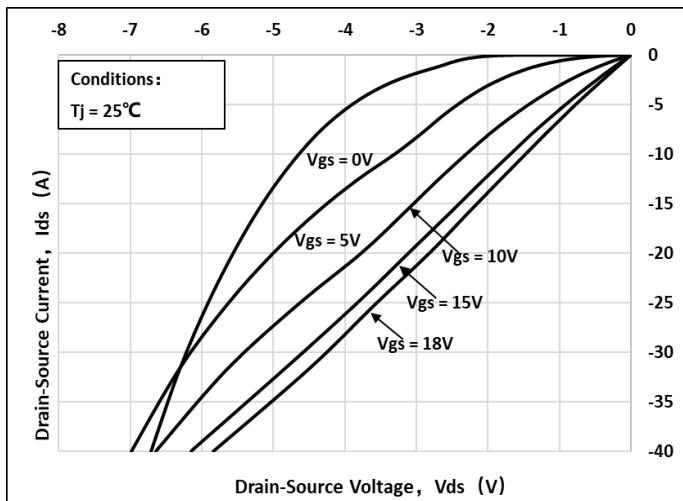
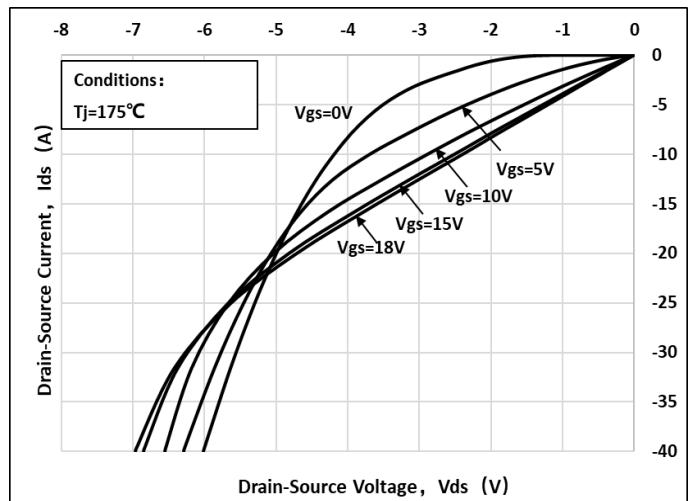
Fig 13: 3rd Quadrant Characteristic($T_J=25^\circ\text{C}$)Fig 14: 3rd Quadrant Characteristic($T_J=175^\circ\text{C}$)

Fig 15: Capacitance Characteristic

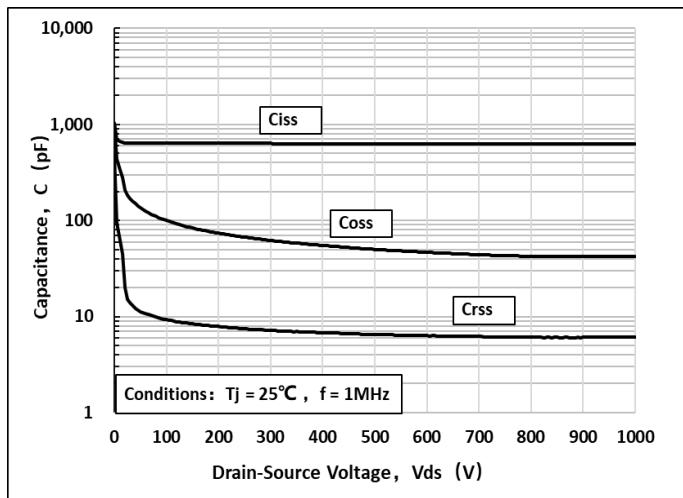


Fig 16: Safe Operating Area

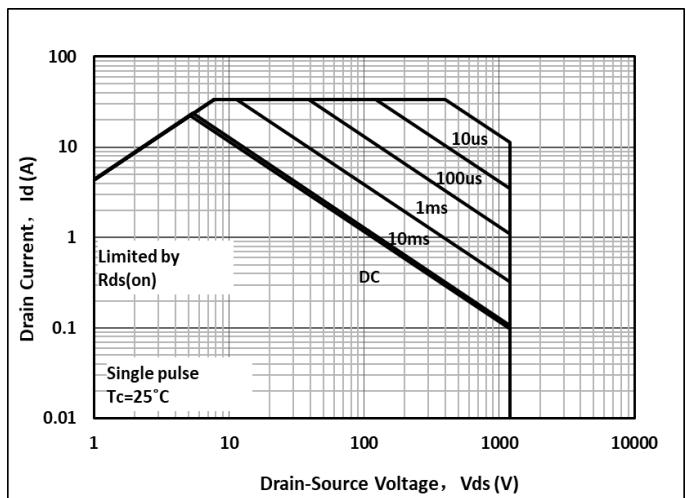
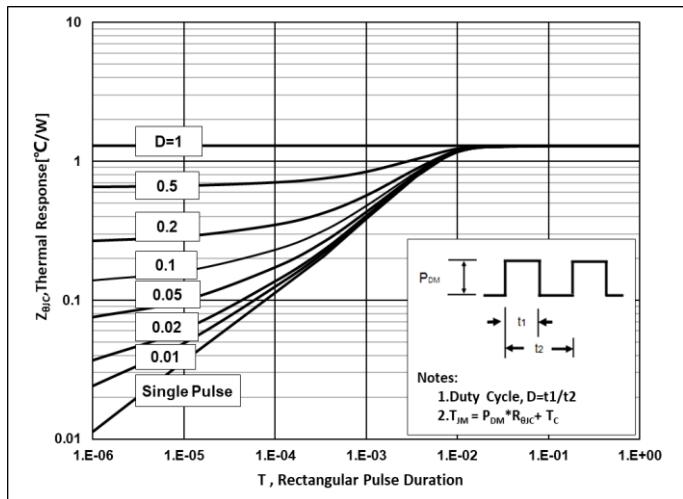


Fig 17: Transient Thermal Impedance



Test Circuit & Waveform

Figure A. Definition of switching times

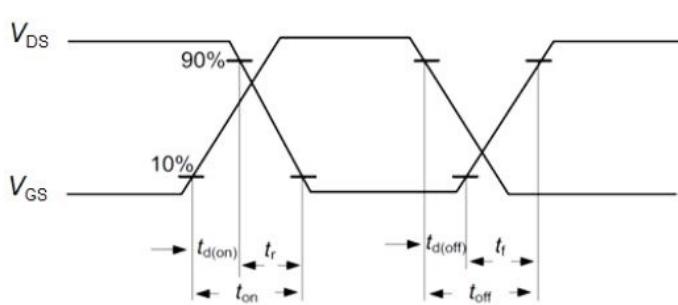


Figure B. Dynamic test circuit

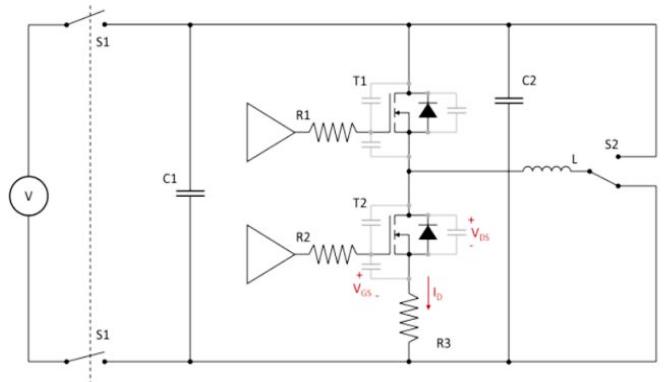


Figure C. Definition of body diodeswitching characteristics

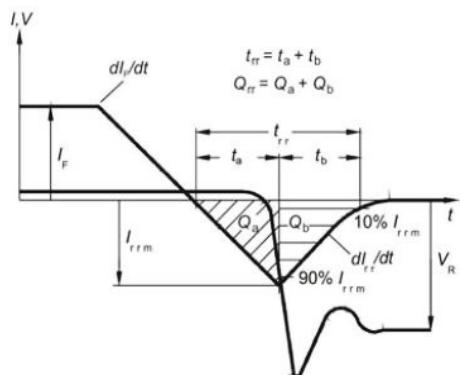
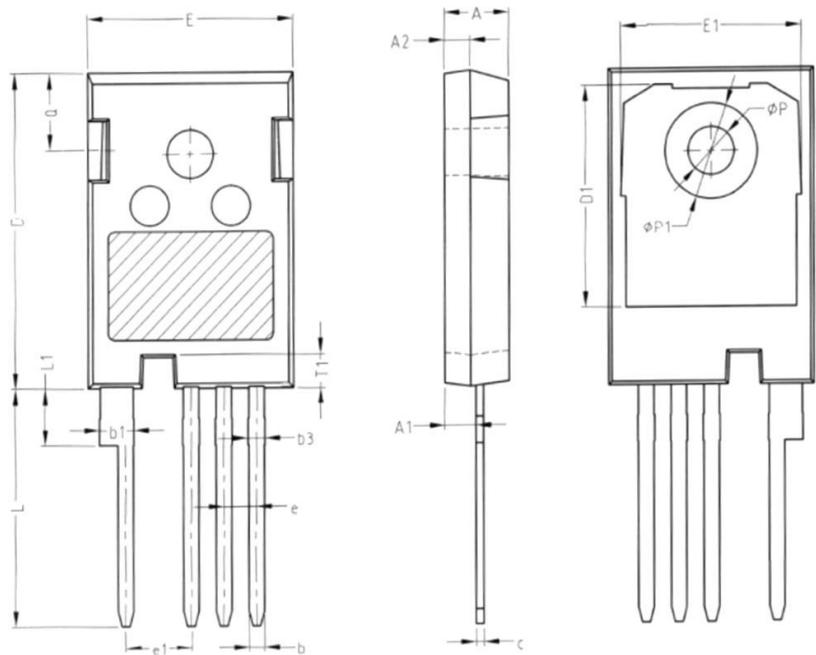


Figure C. Definition of diode switching characteristics

Package Outline:



COMMON DIMENSIONS

SYMBOL	MM		
	MIN	NOM	MAX
A	4.80	5.00	5.20
A1	2.21	2.41	2.61
A2	1.80	2.00	2.20
b	1.06	1.21	1.36
b1	2.33	2.63	2.93
b3	1.07	1.30	1.60
c	0.51	0.61	0.75
D	23.30	23.45	23.60
D1	16.25	16.55	16.85
E	15.74	15.94	16.14
E1	13.72	14.02	14.32
T1	2.35	2.50	2.65
e	2.54 BSC		
e1	5.08 BSC		
Q	5.49	5.79	6.09
L	17.27	17.57	17.87
L1	3.99	4.19	4.39
Φp	3.40	3.60	3.80
Φp1	7.19 REF		

Contact Information

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For additional information, please contact your local Sales Representative.



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